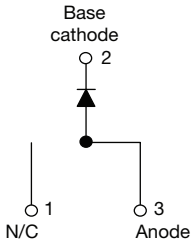
Schottky Rectifier, 8 A



D²PAK



FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- AEC-Q101 qualified

RoHS COMPLIANT
HALOGEN FREE

DESCRIPTION

The VS-8TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

PRODUCT SUMMARY	
$I_{F(AV)}$	8 A
V_R	80 V/100 V

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	8	A
V_{RRM}	Range	80/100	V
I_{FSM}	t_p = 5 µs sine	850	A
V_F	8 Apk, T_J = 125 °C	0.58	V
T_J	Range	- 55 to 175	°C

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-8TQ080SPbF	VS-8TQ100SPbF	UNITS
Maximum DC reverse voltage	V_R	80	100	V
Maximum working peak reverse voltage	V_{RWM}			

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	$I_{F(AV)}$	50 % duty cycle at T_C = 157 °C, rectangular waveform		8	A
Maximum peak one cycle non-repetitive surge current See fig. 7	I_{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	850	A
		10 ms sine or 6 ms rect. pulse		230	
Non-repetitive avalanche energy	E_{AS}	T_J = 25 °C, I_{AS} = 0.50 A, L = 60 mH		7.50	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		0.50	A

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V_{FM} (1)	8 A	T_J = 25 °C	0.72	V
		16 A		0.88	
		8 A	T_J = 125 °C	0.58	
		16 A		0.69	
Maximum reverse leakage current See fig. 2	I_{RM} (1)	T_J = 25 °C	V_R = Rated V_R	0.55	mA
		T_J = 125 °C		7	
Maximum junction capacitance	C_T	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 °C		500	pF
Typical series inductance	L_S	Measured lead to lead 5 mm from package body		8	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/µs

Note

(1) Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T_J, T_{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation See fig. 4	2.0	°C/W
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device			Case style D^2PAK	8TQ080S	
				8TQ100S	

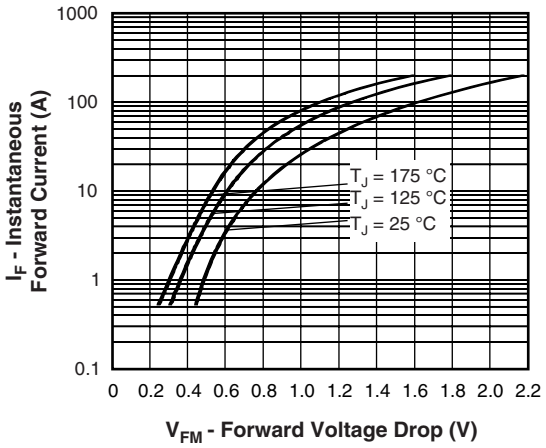


Fig. 1 - Maximum Forward Voltage Drop Characteristics

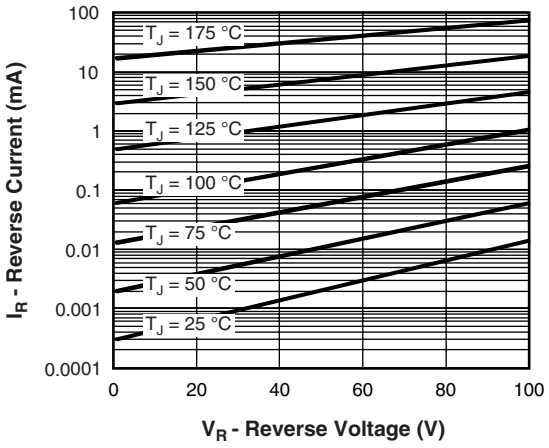


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

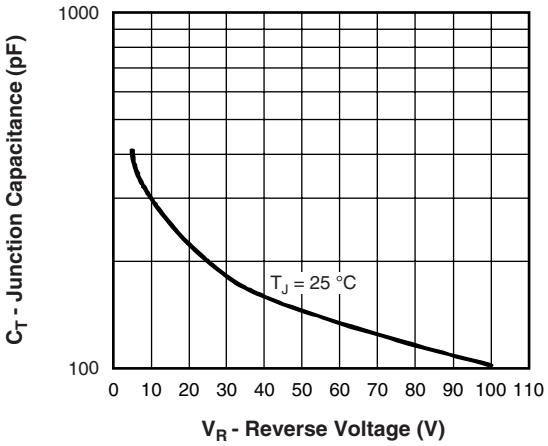


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

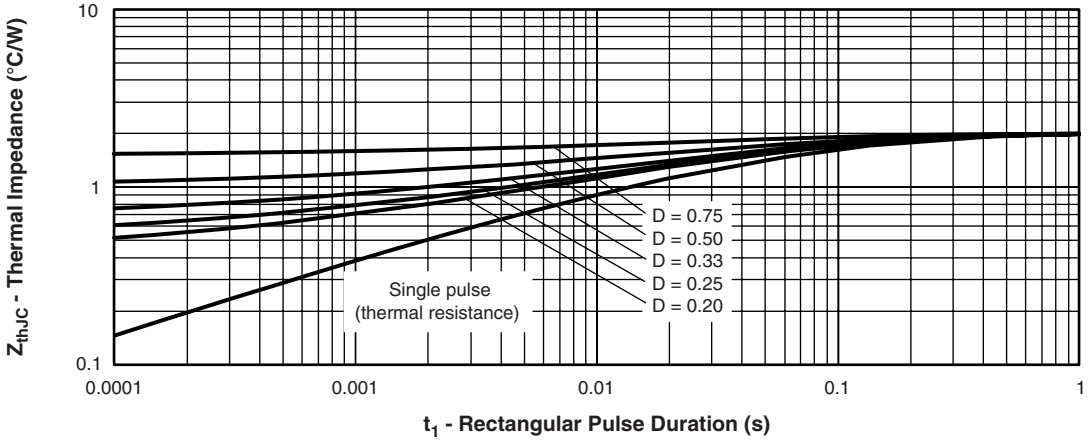


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

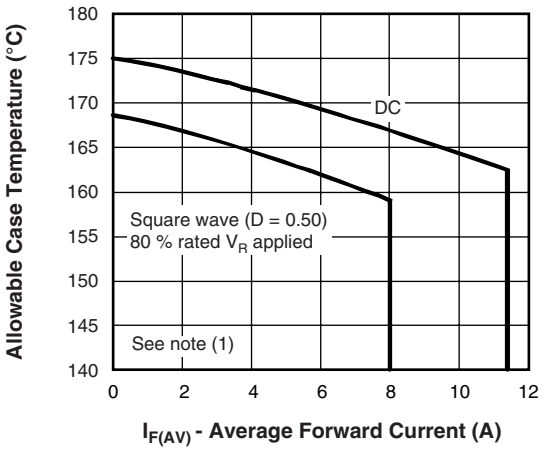


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

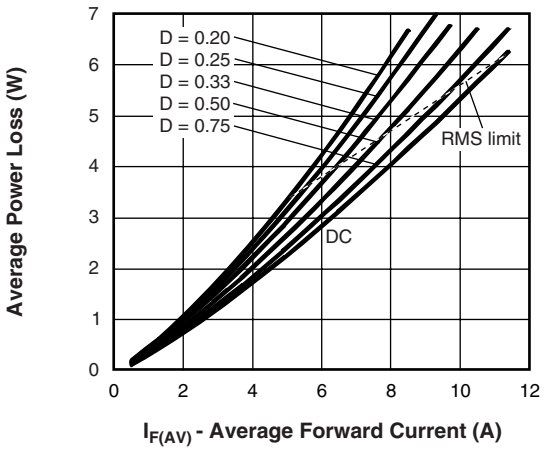


Fig. 6 - Forward Power Loss Characteristics

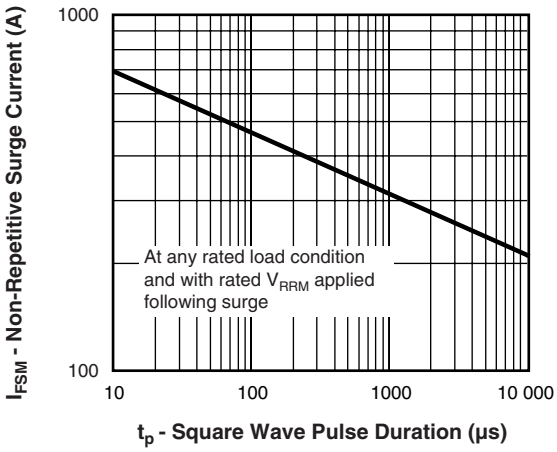


Fig. 7 - Maximum Non-Repetitive Surge Current

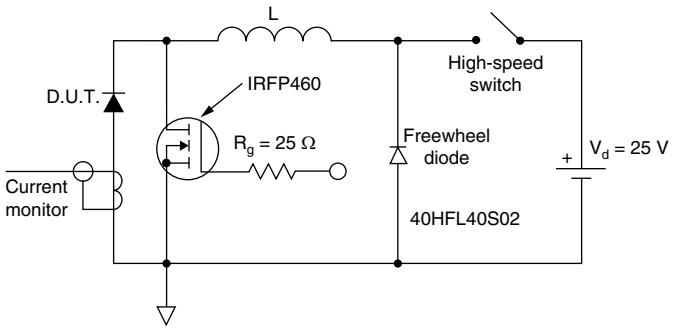


Fig. 8 - Unclamped Inductive Test Circuit

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}$/D) (see fig. 6);
Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

ORDERING INFORMATION TABLE

Device code

VS-	8	T	Q	100	S	TRL	PbF
1	2	3	4	5	6	7	8

1 - HPP product suffix
2 - Current rating (8 A)
3 - Circuit configuration: T = TO-220
4 - Schottky "Q" series
5 - Voltage ratings — 080 = 80 V, 100 = 100 V
6 - S = D^2PAK
7 - • None = Tube (50 pieces)
• TRL = Tape and reel (left oriented)
• TRR = Tape and reel (right oriented)
8 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95046
Part marking information	www.vishay.com/doc?95054
Packaging information	www.vishay.com/doc?95032
SPICE models	www.vishay.com/doc?95291

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